## NSN 5962-01-374-2362

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
4920-00-216-9141
Features Provided:
Bipolar and high speed and high reliability and low current and high current and schottky and electrically alterable and programmed
Inclosure Configuration:
Dual-in-line
Current Rating Per Characteristic:
-30.00 milliamperes collector cutoff current, dc, with specified resistance between base and emitter microamperes and 5.00 milliamperes
reverse current, dc microamperes
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit memory, 512 4 bit bipolar prom
Voltage Rating And Type Per Characteristic:
-0.5 volts total supply and 7.0 volts total supply
Time Rating Per Chacteristic:
40.00 nanoseconds access
Memory Device Type:
Eeprom
Test Data Document:
81349-mil-i-43553 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883
standard (includes industry or association standards, individual manufactureer standards, etc.). And 96906-mil-std-130 standard (includes
industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
16 printed circuit
Purchase Description Identification:
S7040-mc8304420-0
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli Fiig:

Demilitarization:

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